

## DESCRIPTION

The ESDA6V1L is a dual monolithic voltage suppressor designed to protect components which are connected to data and transmission lines against ESD. It clamps the voltage just above the logic level supply for positive transients and to a diode drop below ground for negative transients. It can also work as bidirectional suppressor by connecting only pin1 and 2.

## APPLICATIONS

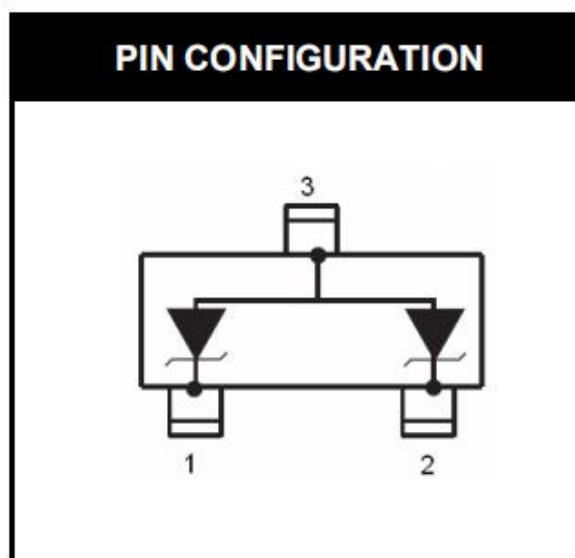
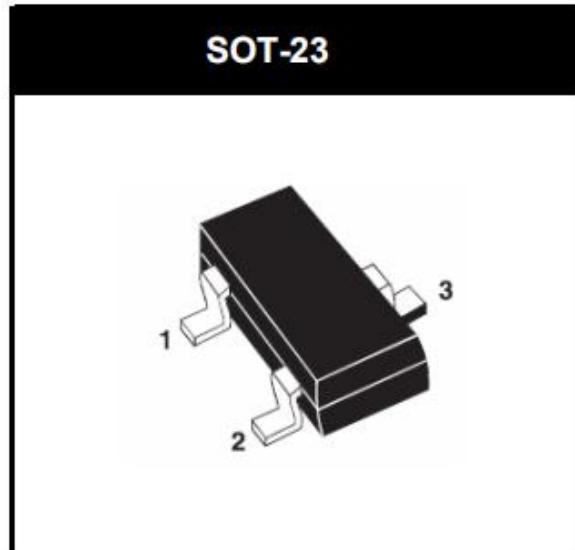
- ✧ Computers.
- ✧ Printers.
- ✧ Communication systems.
- ✧ It is particularly recommended for the RS232 I/O. port protection where the line interface withstands only with 2kV ESD surges.

## FEATURES

- ✧ 2 Unidirectional Transil functions
- Low leakage current: IRM max< 1  $\mu$ A at VRM.
- ✧ 300W peak pulse power(8/20 $\mu$ s).

## COMPLIES WITH THE FLOWING STANDARDS

- ✧ IEC61000-4-2.
- ✧ Level 4 15 kV (air discharge)  
8 kV(contact discharge) .
- ✧ MIL STD 883E - Method 3015-7 Class 3  
25 kV HBM (Human Body Model) .



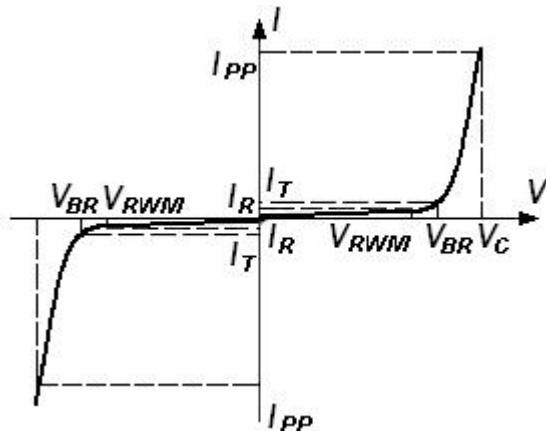
## DEVICE CHARACTERISTICS

### Absolute Ratings (Tamb=25°C)

Symbol	Parameter	Value	Units
P <sub>pp</sub>	Peak Pulse Power (tp = 8/20μs)	300	W
T <sub>L</sub>	Maximum lead temperature for soldering during 10s	260	°C
T <sub>stg</sub>	Storage Temperature Range	-55 to +155	°C
T <sub>OP</sub>	Operating Temperature Range	-40 to +125	°C
T <sub>j</sub>	Maximum junction temperature	150	°C
V <sub>PP</sub>	Electrostatic discharge MIL STD 883C -Method 3015-6 IEC61000-4-2 air discharge IEC61000-4-2 contact discharge	25 15 8	kV

## ELECTRICAL PARAMETER

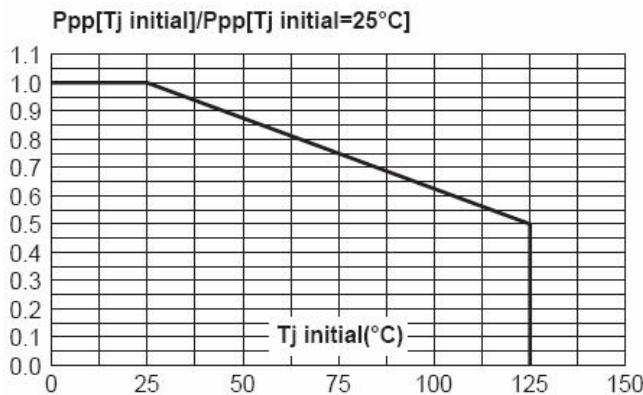
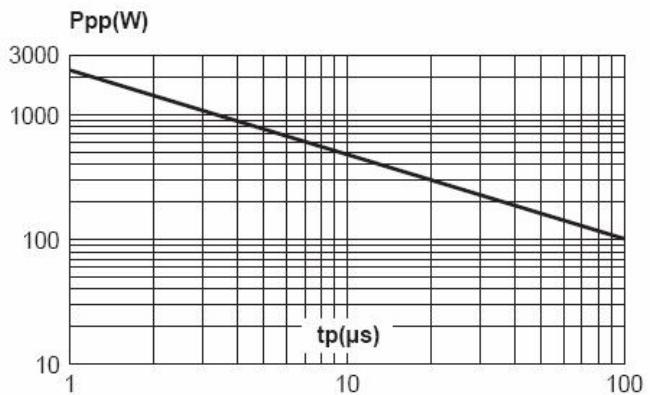
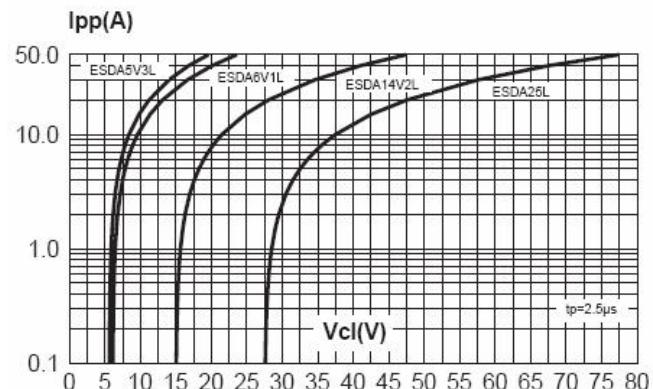
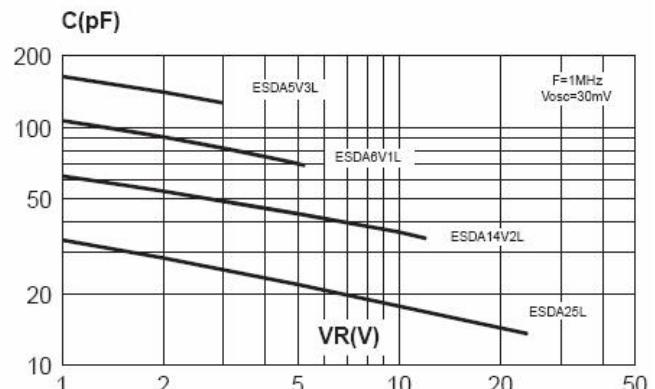
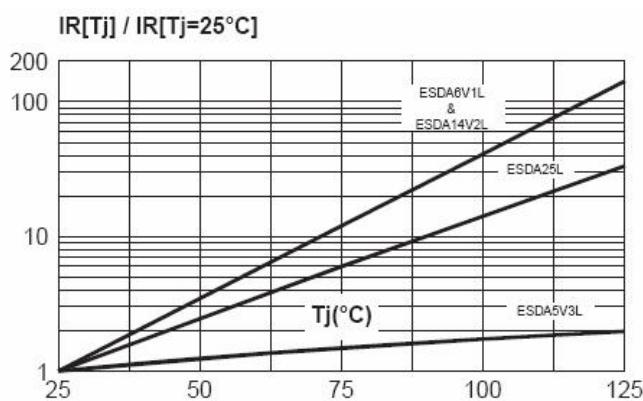
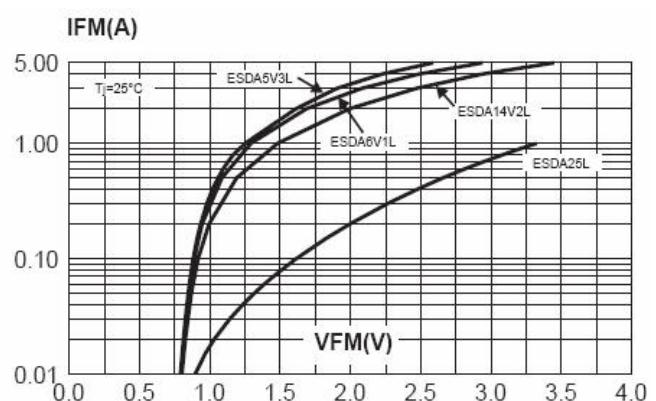
Symbol	Parameter
I <sub>pp</sub>	Maximum Reverse Peak Pulse Current
V <sub>c</sub>	Clamping Voltage @ I <sub>pp</sub>
V <sub>RWM</sub>	Working Peak Reverse Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>
I <sub>T</sub>	Test Current
V <sub>BR</sub>	Breakdown Voltage @ I <sub>t</sub>

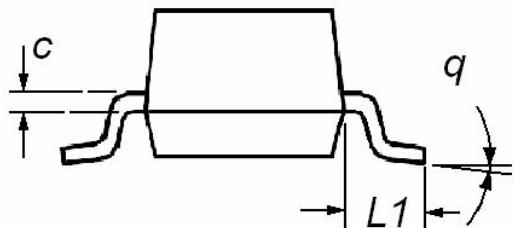
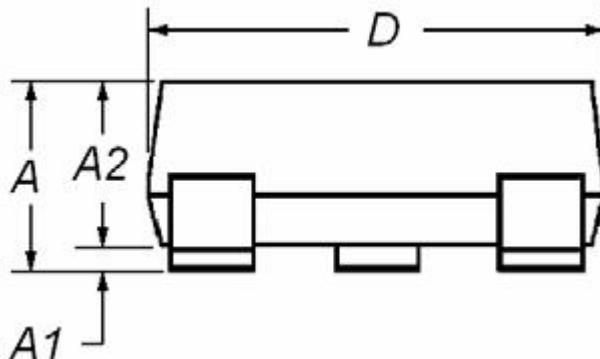
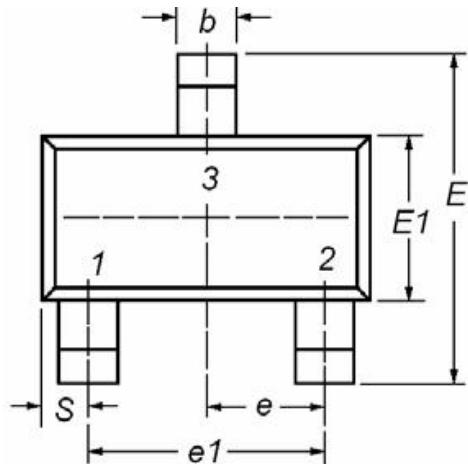


## ELECTRICAL CHARACTERISTICS

Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified. VF = 0.9V at IF = 10mA)							
Part Numbers	V <sub>BR</sub>			I <sub>T</sub>	V <sub>RWM</sub>	I <sub>R</sub>	C
	Min.	Typ.	Max.				Typ. 0v bias
	V	V	V		mA	V	μA
ESDA6V1L	6.1	6.7	7.2	1	5.25	20	20

1. Square pulse IPP=15A, tp=2.5μs
2. △VBR=aT\*(Tamb-25°C)\*VBR(25°C)
3. Capacitance is measured by pin 1 to pin 3 or pin2 to pin 3.

**TYPICAL CHARACTERISTICS**

**Fig1. Peak power dissipation versus Initial junction temperature**

**Fig2. Peak pulse power versus exponential pulse duration(T<sub>j</sub> initial=25°C)**

**Fig3. Clamping voltage versus peak pulse current (T<sub>j</sub> initial=25°C, rectangular Waveform,t<sub>p</sub>=2.5μs)**

**Fig4. Capacitance versus reverse Applied voltage**

**Fig5. Relative variation of leakage current Versus junction temperature**

**Fig6. Peak forward voltage drop versus peak forward current**

**SOT-23 MECHNICAL DATA**


Dim	Millimeters		
	Min	TYP	Max
A	1.00	1.20	1.40
A1	0	0.05	0.10
A2	1.00	1.15	1.30
b	0.35	0.40	0.50
c	0.10	0.15	0.20
D	2.70	2.90	3.10
E	2.40	2.60	2.80
E1	1.40	1.50	1.60
e	0.85	1.00	1.15
e1	1.80	1.90	2.00
L1	0.40		
q	$0^\circ$	$5^\circ$	$10^\circ$
S	0.45	0.50	0.55

 Website: <http://www.jksemi.com>

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